

RS4G125 Quadruple Bus Buffer Gate With 3-State Outputs

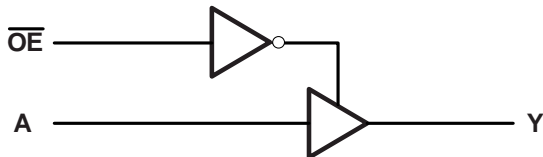
FEATURES

- Operating Voltage Range:1.65V to 5.5V
- Low Power Consumption:1μA (Max)
- Operating Temperature Range:
-40°C to +125°C
- Inputs Accept Voltage to 5.5V
- ±24mA Output Drive at V_{CC}=3.0V
- Latch-up Performance Exceeds 100mA
- PACKAGES: SOIC-14(SOP14) and TSSOP-14

APPLICATIONS

- AV Receiver
- Cable Modem Termination Systems
- Digital Picture Frame (DPF)
- High-Speed Data Acquisition and Generation
- Motor Controls: High-Voltage
- Personal Navigation Device (GPS)
- Portable Media Player
- Video Communication Systems

Simplified Schematic



DESCRIPTION

The quadruple buffer is designed for 1.65V to 5.5V V_{CC} operation. The RS4G125 device is quadruple line drivers with 3-state outputs. The outputs are disabled when the output-enable (\overline{OE}) input is high.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor, the minimum value of the resistor is determined by the current-sinking capability of the driver.

The RS4G125 is available in Green SOIC-14(SOP14) and TSSOP-14 packages. It operates over an ambient temperature range of -40°C to +125°C.

Device Information ⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
RS4G125	SOIC-14(SOP14)	8.65mm×3.90mm
	TSSOP-14	5.00mm×4.40mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

FUNCTION TABLE

INPUTS		OUTPUT
\overline{OE}	A	Y
L	H	H
L	L	L
H	X	Z

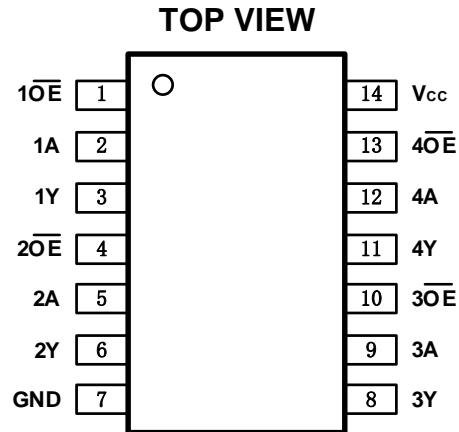
H=HIGH Logic Level
L =LOW Logic Level
X=Don't Care
Z=High-impedance OFF-state

Revision History

Note: Page numbers for previous revisions may differ from page numbers in the current version.

Version	Change Date	Change Item
A.1	2021/2/5	Initial version completed

PIN CONFIGURATIONS



PIN DESCRIPTION

PIN	NAME	I/O TYPE	FUNCTION
SOIC-14(SOP14)/TSSOP-14			
1	$\overline{1OE}$	I	Output Enable for buffer 1
2	1A	I	Input of buffer 1
3	1Y	O	Output of buffer 1
4	$\overline{2OE}$	I	Output Enable for buffer 2
5	2A	I	Input of buffer 2
6	2Y	O	Output of buffer 2
7	GND	-	Ground
8	3Y	O	Output of buffer 3
9	3A	I	Input of buffer 3
10	$\overline{3OE}$	I	Output Enable for buffer 3
11	4Y	O	Output of buffer 4
12	4A	I	Input of buffer 4
13	$\overline{4OE}$	I	Output Enable for buffer 4
14	Vcc	-	Power Supply

Specifications

Absolute Maximum Ratings ⁽¹⁾

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾⁽²⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage range	-0.5	6.5	V
V _I	Input voltage range ⁽²⁾	-0.5	6.5	V
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
V _O	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾	-0.5	V _{CC} +0.5	V
I _{IK}	Input clamp current	V _I <0	-50	mA
I _{OK}	Output clamp current	V _O <0	-50	mA
I _O	Continuous output current		±50	mA
	Continuous current through V _{CC} or GND		±100	mA
T _J	Junction temperature	-65	150	°C
T _{stg}	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the *Recommended Operating Conditions table*.

ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM)	±8000
		Machine model (MM)	±500

Thermal Information:

THERMAL METRIC ⁽¹⁾		RS4G125		UNIT
		14PINS		
		SOIC-14(SOP14)	TSSOP-14	
R _{θJA}	Junction-to-ambient thermal resistance	122.2	141.2	°C/W
R _{θJC(top)}	Junction-to-case(top) thermal resistance	80.9	78.8	°C/W
R _{θJB}	Junction-to-board thermal resistance	80.6	85.8	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	40.4	27.7	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	80.3	85.5	°C/W
R _{θJC(bot)}	Junction-to-case(bottom) thermal resistance	N/A	N/A	°C/W

PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING ⁽¹⁾	PACKAGE OPTION
RS4G125	RS4G125XP	-40°C ~+125°C	SOIC-14(SOP14)	RS4G125	Tape and Reel,4000
	RS4G125XQ	-40°C ~+125°C	TSSOP-14	RS4G125	Tape and Reel,4000

NOTE:

- (1) There may be additional marking, which relates to the lot trace code information(data code and vendor code), the logo or the environmental category on the device.

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (TYP values are at $T_A = +25^\circ\text{C}$, unless otherwise noted.) ⁽¹⁾

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply voltage	V_{CC}	Operating	1.65	5.5	V
		Data retention only	1.5	5.5	
High-level input voltage	V_{IH}	$V_{CC}=1.65\text{V to }1.95\text{V}$	$0.65 \times V_{CC}$		V
		$V_{CC}=2.3\text{V to }2.7\text{V}$	1.7		
		$V_{CC}=3\text{V to }3.6\text{V}$	2.2		
		$V_{CC}=4.5\text{V to }5.5\text{V}$	$0.7 \times V_{CC}$		
Low-level input voltage	V_{IL}	$V_{CC}=1.65\text{V to }1.95\text{V}$		$0.15 \times V_{CC}$	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$		0.3	
		$V_{CC}=3\text{V to }3.6\text{V}$		0.4	
		$V_{CC}=4.5\text{V to }5.5\text{V}$		$0.15 \times V_{CC}$	
Input voltage	V_I		0	5.5	V
Output voltage	V_O		0	V_{CC}	V
Input transition rise or fall	t_r, t_f	$V_{CC}=1.8\text{V} \pm 0.15\text{V}, 2.5\text{V} \pm 0.2\text{V}$		20	ns/V
		$V_{CC}=3.3\text{V} \pm 0.3\text{V}$		10	
		$V_{CC}=5\text{V} \pm 0.5\text{V}$		5	
Operating temperature	T_A		-40	+125	$^\circ\text{C}$

Electrical Characteristics

PARAMETER	TEST CONDITIONS	V_{CC}	TEMP	MIN	TYP	MAX	UNIT	
V_{OH}	$I_{OH} = -100\mu\text{A}$	1.65V to 5.5V	Full	$V_{CC}-0.1$			V	
	$I_{OH} = -4\text{mA}$	1.65V		1.2				
	$I_{OH} = -8\text{mA}$	2.3V		1.9				
	$I_{OH} = -16\text{mA}$	3V		2.4				
	$I_{OH} = -24\text{mA}$			2.3				
	$I_{OH} = -32\text{mA}$	4.5V		3.8				
V_{OL}	$I_{OL} = 100\mu\text{A}$	1.65V to 5.5V	Full			0.1	V	
	$I_{OL} = 4\text{mA}$	1.65V				0.45		
	$I_{OL} = 8\text{mA}$	2.3V				0.3		
	$I_{OL} = 16\text{mA}$	3V				0.4		
	$I_{OL} = 24\text{mA}$					0.55		
	$I_{OL} = 32\text{mA}$	4.5V				0.55		
I_i	A or \overline{OE} inputs	$V_I=5.5\text{V or GND}$	0V to 5.5V	+25 $^\circ\text{C}$		± 0.1	± 1	μA
				Full			± 5	
I_{off}	V_I or $V_O=5.5\text{V}$	0V	+25 $^\circ\text{C}$		± 0.1	± 1	μA	
			Full			± 10		
I_{oz}	$V_O=0\text{V to }5.5\text{V}$	3.6V	Full			10	μA	
I_{CC}	$V_I=5.5\text{V or GND}, I_o=0$	1.65V to 5.5V	+25 $^\circ\text{C}$		0.1	1	μA	
			Full			10		
ΔI_{CC}	One input at $V_{CC}-0.6\text{V}$, Other inputs at V_{CC} or GND	3V to 5.5V	Full			500	μA	

Switching Characteristics, $C_L=15\text{pF}$

 over recommended operating free-air temperature range (-40°C to 125°C, unless otherwise noted.) ⁽¹⁾

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}=1.8\text{V} \pm 0.15\text{V}$	$V_{CC}=2.5\text{V} \pm 0.2\text{V}$	$V_{CC}=3.3\text{V} \pm 0.3\text{V}$	$V_{CC}=5\text{V} \pm 0.5\text{V}$	UNIT
			TYP	TYP	TYP	TYP	
t_{pd}	A	Y	6.1	3.7	3.9	2.1	ns

Switching Characteristics, $C_L=30\text{pF}$ or 50pF

 over recommended operating free-air temperature range (-40°C to 125°C, unless otherwise noted.) ⁽¹⁾

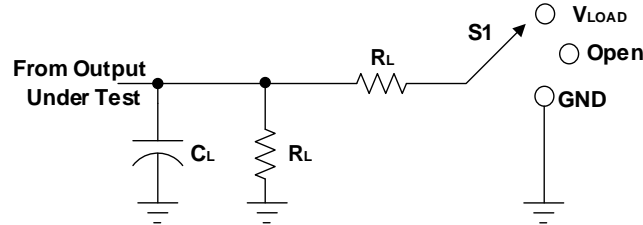
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}=1.8\text{V} \pm 0.15\text{V}$	$V_{CC}=2.5\text{V} \pm 0.2\text{V}$	$V_{CC}=3.3\text{V} \pm 0.3\text{V}$	$V_{CC}=5\text{V} \pm 0.5\text{V}$	UNIT
			TYP	TYP	TYP	TYP	
t_{pd}	A	Y	8.6	5.3	4.0	2.9	ns
t_{en}	\overline{OE}	Y	9.5	5.8	5.0	3.3	ns
t_{dis}	\overline{OE}	Y	7.4	4.3	4.4	3.0	ns

Operating Characteristics
 $T_A=25^\circ\text{C}$

PARAMETER			TEST CONDITIONS	$V_{CC}=1.8\text{V}$	$V_{CC}=2.5\text{V}$	$V_{CC}=3.3\text{V}$	$V_{CC}=5\text{V}$	UNIT
				TYP	TYP	TYP	TYP	
C_{pd}	Power dissipation capacitance	Output enabled	f=10MHZ	18	18	19	21	pF
		Output disabled		2	2	2	4	

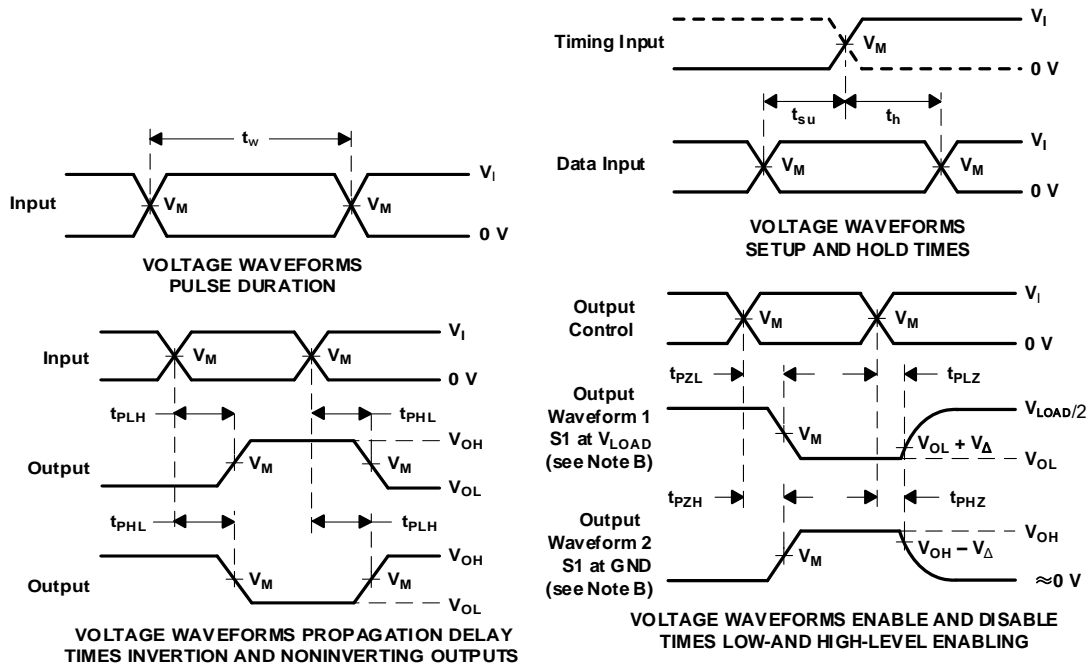
 (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Parameter Measurement Information



TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_I	t_r/t_f					
$1.8V \pm 0.15V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M Ω	0.15V
$2.5V \pm 0.2V$	V_{CC}	$\leq 2ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M Ω	0.15V
$3.3V \pm 0.3V$	3V	$\leq 2.5ns$	1.5V	6V	15pF	1M Ω	0.3V
$5V \pm 0.5V$	V_{CC}	$\leq 2.5ns$	$V_{CC}/2$	$2 \times V_{CC}$	15pF	1M Ω	0.3V

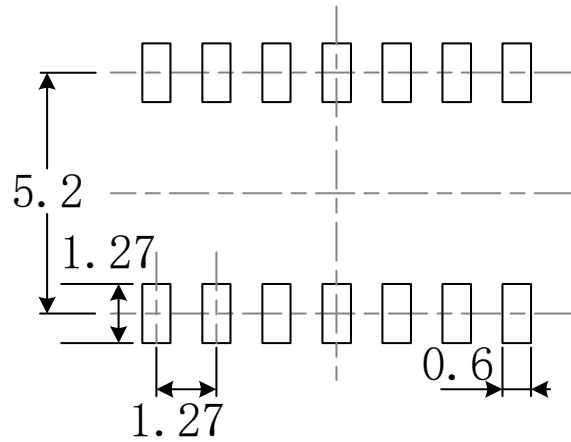
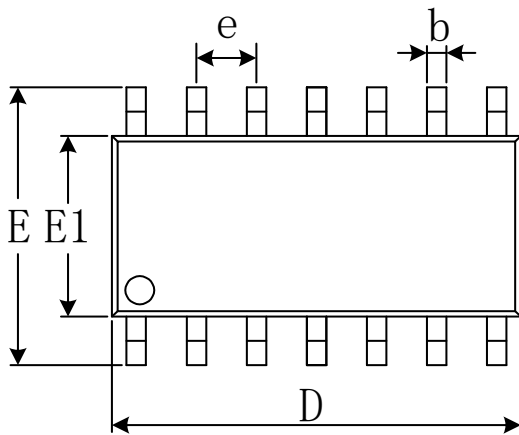


- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$.
 D. The outputs are measured one at a time, with one transition per measurement.
 E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 F. t_{PZL} and t_{PZH} are the same as t_{on} .
 G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 H. All parameters and waveforms are not applicable to all devices.

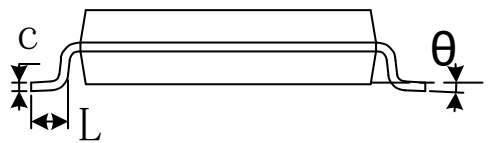
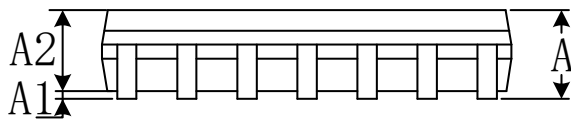
Figure 1. Load Circuit and Voltage Waveforms

PACKAGE OUTLINE DIMENSIONS

SOIC-14(SOP14)

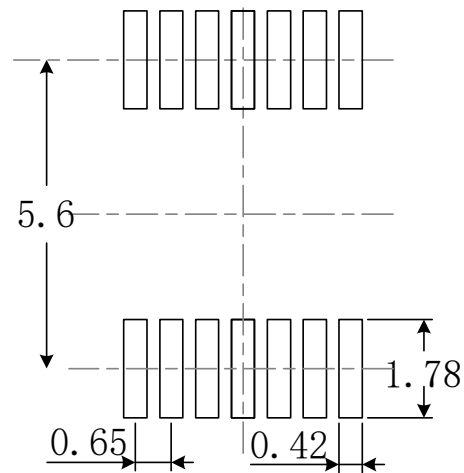
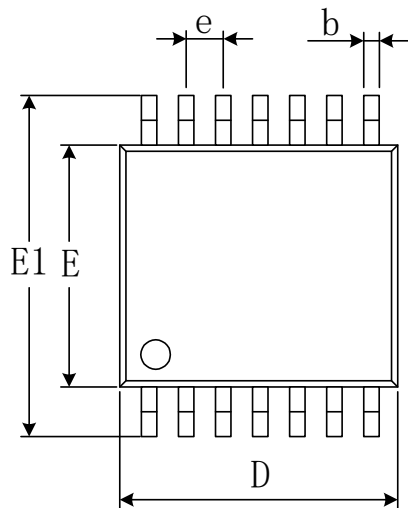


RECOMMENDED LAND PATTERN (Unit: mm)

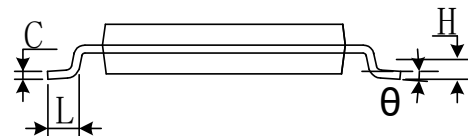
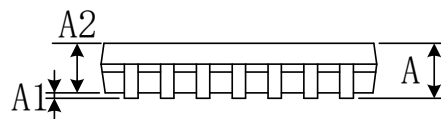


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D	8.450	8.850	0.333	0.348
e	1.270(BSC)		0.050(BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

TSSOP-14



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650(BSC)		0.026(BSC)	
L	0.500	0.700	0.020	0.028
H	0.25(TYP)		0.01(TYP)	
θ	1°	7°	1°	7°